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# Local/Remote Temperature Switches in a µMAX Package

### **General Description**

The MAX6687/MAX6688 comprise a remote-junction temperature switch and a local temperature switch in a single package. The remote-junction switch uses an external P-N junction (typically a diode-connected transistor on the die of an external CPU, ASIC, or FPGA) as a sensing element to measure the remote temperature. The remote-junction temperature switch has a factory-programmed trip temperature threshold of either +120°C or +125°C. The local temperature switch has a pin-programmable temperature threshold that is set by connecting pins S1 and S2 to ground, to V<sub>DD</sub>, or leaving them floating. Hysteresis for both local and remote thresholds is  $5^{\circ}$ C. The MAX6687/MAX6688 do not assert on transient (single-sample) faults or when power is first applied.

The MAX6687 has two open-drain active-low outputs while the MAX6688 has two push-pull active-high outputs. T<sub>REMOTE</sub> asserts a logic signal when the remote temperature exceeds the factory-programmed +120°C or +125°C trip threshold. T<sub>LOCAL</sub> is asserted when the die temperature exceeds the pin-programmed threshold, which is controlled by pins S1 and S2. The local thresholds are available in two ranges in 5°C increments. The two ranges are +40°C to +80°C and +75°C to +115°C.

The MAX6687/MAX6688 operate from a 3.0V to 5.5V power supply and are available in a space-saving 8-pin  $\mu$ MAX package.

#### Applications

CPU Temperature Protection FPGA Temperature Protection Fan Control Temperature Alarms

#### **Features**

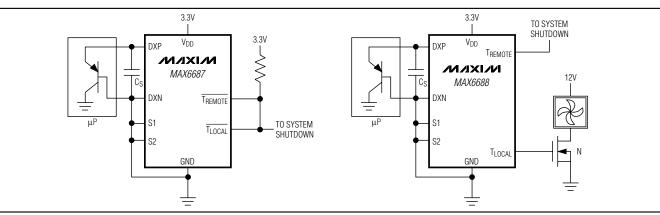
- Pin-Programmable Local Temperature Threshold in 5°C Increments in Two Distinct Ranges: +40°C to +80°C and +75°C to +115°C
- Factory-Programmed Remote Threshold: +120°C (L Suffix) or +125°C (H Suffix)
- Open-Drain Active-Low Outputs (MAX6687)
- ♦ CMOS Push-Pull, Active-High Outputs (MAX6688)
- ♦ ±1.5°C Accuracy
- ♦ 2Hz Temperature Sampling Rate
- ♦ 215µA Average Supply Current
- ♦ 3.0V to 5.5V Power-Supply Voltage
- ♦ 8-Pin µMAX Package

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PART	TEMP RANGE	PIN-PACKAGE
MAX6687AU40L	-40°C to +125°C	8 µMAX
MAX6687AU40H	-40°C to +125°C	8 µMAX
MAX6687AU75L	-40°C to +125°C	8 µMAX
MAX6687AU75H	-40°C to +125°C	8 µMAX
MAX6688AU40L	-40°C to +125°C	8 µMAX
MAX6688AU40H	-40°C to +125°C	8 µMAX
MAX6688AU75L	-40°C to +125°C	8 µMAX
MAX6688AU75H	-40°C to +125°C	8 µMAX

Pin Configurations/Functional Diagrams/Selector Guide appear at end of data sheet.

## **Typical Operating Circuit**

**Ordering Information** 



\_ Maxim Integrated Products 1

#### **ABSOLUTE MAXIMUM RATINGS**

Voltages Referenced to GND	Continuous Power Dissipation ( $T_A = +70^{\circ}C$ )
VDD, TLOCAL, TREMOTE0.3V to +6V	8-Pin µMAX (derate 4.1mW/°C above +70°C)
DXN0.3V to +0.8V	Operating Temperature Range40°C to +125°C
All Other Pins0.3V to (V <sub>DD</sub> + 0.3V)	Junction Temperature+150°C
Input Current5mA	Storage Temperature Range65°C to +165°C
Output Current20mA	Lead Temperature (soldering, 10s)+300°C

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

#### **ELECTRICAL CHARACTERISTICS**

 $(V_{DD} = 3V \text{ to } 5.5V, T_A = -40^{\circ}C \text{ to } +125^{\circ}C, \text{ unless otherwise noted. Typical values are at } V_{DD} = 3.3V \text{ and } T_A = +25^{\circ}C.)$  (Note 1)

PARAMETER	SYMBOL	CONDITION	MIN	ТҮР	МАХ	UNITS	
Power-Supply Range	V <sub>DD</sub>		3		5.5	V	
Average Supply Current	I <sub>DD</sub>			215	500	μA	
Supply Current During Conversion				400	800	μA	
Power-On Reset (POR) Threshold	POR	V <sub>DD</sub> falling edge	1	1.5	2.0	V	
POR Threshold Hysteresis				50		mV	
Remote-Diode Temperature		$T_A = +25^{\circ}C, V_{DD} = 3.3V$	-1.5		+1.5		
Threshold Accuracy, Rising	$\Delta T_{TH}$	$T_A = 0^{\circ}C$ to +85°C, $V_{DD} = 3.3V$	-3.0		+3.0	°C	
Temperature		$T_A = -40^{\circ}C \text{ to } +125^{\circ}C, V_{DD} = 3.3V$	-5.0		+5.0		
Internal Temperature Threshold	ΔT <sub>TH</sub>	Temperature trip thresholds from +40°C to $+105$ °C, V <sub>DD</sub> = 3.3V	-3.0		+3.0		
Accuracy, Rising Temperature		Temperature trip thresholds +110°C and +115°C, $V_{DD} = 3.3V$	-3.5		+3.5	°C	
Temperature Threshold Hysteresis	T <sub>HYST</sub>			5.0		°C	
Temperature Threshold Supply Sensitivity					0.6	°C/V	
Output Voltage High	VOH	ISOURCE = 1mA, MAX6688	V <sub>DD</sub> - 0.2			V	
Output Voltage Low	VOL	I <sub>SINK</sub> = 1mA			0.2	V	
Logic Input Low Voltage (S1, S2)	VIL				0.4	V	
Logic Input High Voltage (S1, S2)	VIH		1.8			V	
Input Current (S1, S2)					10	μA	
Open-Drain Output Leakage Current		V <sub>OUT</sub> = 5.5V, MAX6687			1	μA	

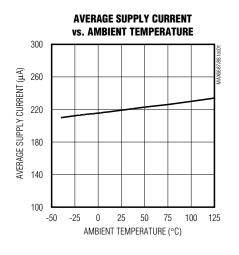
### **ELECTRICAL CHARACTERISTICS (continued)**

 $(V_{DD} = 3V \text{ to } 5.5V, T_A = -40^{\circ}\text{C} \text{ to } +125^{\circ}\text{C}, \text{ unless otherwise noted. Typical values are at } V_{DD} = 3.3V \text{ and } T_A = +25^{\circ}\text{C}.)$  (Note 1)

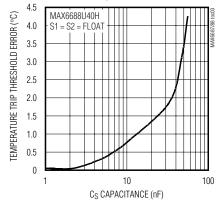
PARAMETER	SYMBOL	CONDITION	MIN	ТҮР	MAX	UNITS
Temperature Conversion Time			0.2	0.25	0.3	S
Temperature Sample Period			0.4	0.5	0.6	S
Current Sourcing for External		High level	80	100	120	
Diode		Low level	8	10	12	μA

Note 1: All parameters are tested at +25°C. Temperature specifications over a range of -40°C to +125°C are guaranteed by design.

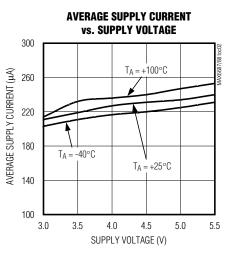
(V<sub>DD</sub> = 3.3V, C<sub>S</sub> = 2200pF, T<sub>A</sub> =  $+25^{\circ}C$ , unless otherwise noted.)



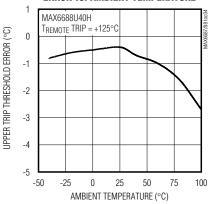
TEMPERATURE TRIP THRESHOLD ERROR vs. C<sub>S</sub> CAPACITANCE



## **Typical Operating Characteristics**



REMOTE TEMPERATURE TRIP THRESHOLD ERROR vs. AMBIENT TEMPERATURE



MAX6687/MAX6688

**Pin Description** 

PIN		NAME	FUNCTION		
MAX6687	6687 MAX6688				
1	1	V <sub>DD</sub>	Power-Supply Input. Bypass to GND with a 0.1µF capacitor.		
2	2	GND	Ground		
3	3	DXP	This pin connects to the positive (anode) terminal of the external P-N sense junction. It sources current into the external junction. A 2200pF capacitor should be connected across DXP and DXN.		
4	4	DXN	This pin connects to the negative (cathode) terminal of the external P-N sense junction. It sind current from the external junction. A 2200pF capacitor should be connected across DXP and DXN. DXN must be connected to the GND pin at the pin.		
5	_	TREMOTE	Open-Drain Active-Low Output. $\overline{T_{\text{REMOTE}}}$ goes low when the temperature exceeds the factory- programmed temperature threshold, either +120°C or +125°C. Connect a pullup resistor (typically 10k $\Omega$ ) between $\overline{T_{\text{REMOTE}}}$ and a positive power supply up to 5.5V.		
_	5	TREMOTE	CMOS Push-Pull, Active-High Output. T <sub>REMOTE</sub> goes high when the temperature exceeds the factory-programmed temperature threshold, either +120°C or +125°C.		
6	_	TLOCAL	Open-Drain Active-Low Output. $\overline{T_{LOCAL}}$ goes low when the temperature exceeds the pin- programmable temperature threshold set by S1 and S2. Connect a pullup resistor (typically $10k\Omega$ ) between $\overline{T_{LOCAL}}$ and a positive power supply up to 5.5V.		
	6	T <sub>LOCAL</sub>	CMOS Push-Pull, Active-High Output. T <sub>LOCAL</sub> goes high when the temperature exceeds the pin-programmable temperature threshold set by S1 and S2.		
7	7	S1	Threshold Select Input. Used in conjunction with S2 to set the local threshold temperature (Table 1). It can be connected to $V_{DD}$ , GND, or left floating.		
8	8	S2	Threshold Select Input. Used in conjunction with S1 to set the local threshold temperature (Table 1). It can be connected to $V_{DD}$ , GND, or left floating.		

#### **Detailed Description**

The MAX6687/MAX6688 sense the temperatures of both a remote P-N junction and their own die. The external P-N junction is typically a base-emitter junction of a substrate PNP on a microprocessor, FPGA, or ASIC die (see the *Typical Operating Circuit*).

The remote temperature switch has a factory-programmed trip temperature of either +120°C or +125°C and is intended to be used for system shutdown when the die temperature of a remote IC, such as a microprocessor, FPGA, or ASIC exceeds the factory-programmed thresholds.

The local temperature switch has a pin-programmable threshold temperature (Table 1). This temperature switch may be used for such functions as system shutdown or for turning on a cooling fan when board temperature exceeds the temperature limit. Two temperature ranges are available for the local trip threshold: +40°C to +80°C and +75°C to +115°C. S1 and S2 pins must be set to the desired trip temperature before power is applied to the  $V_{DD}$  pin. If S1 and S2 settings are changed after the power is turned on, the local trip threshold remains set to the point where S1 and S2 were when power was applied.

Since the MAX6687/MAX6688 are often used for system shutdown, they are designed so that the outputs do not change on transient faults or when power is first applied. This eliminates the possibility that the IC could erroneously shut a system down.

The MAX6687/MAX6688 provide noise immunity by integration and oversampling of the diode voltage, but good design practice includes routing the DXP and DXN lines away from noise sources, such as high-speed digital lines, switching regulators, inductors, and transformers. The DXP and DXN traces should be paired together and surrounded by a ground plane whenever possible.

S1 S2		MAX6687AUA40L/MAX6687AUA40H/ MAX6688AUA40L/MAX6688AUA40H	MAX6687AUA75L/MAX6687AUA75H/ MAX6688AUA75L/MAX6688AUA75H		
		LOCALTEMPERATURE TRIP THRESHOLD (°C)	LOCAL TEMPERATURE TRIP THRESHOLD (°C)		
GND	GND	+40	+75		
GND	FLOAT	+45	+80		
GND	V <sub>DD</sub>	+50	+85		
FLOAT	GND	+55	+90		
FLOAT	FLOAT	+60	+95		
FLOAT	V <sub>DD</sub>	+65	+100		
V <sub>DD</sub>	GND	+70	+105		
V <sub>DD</sub>	FLOAT	+75	+110		
V <sub>DD</sub>	V <sub>DD</sub>	+80	+115		

#### Table 1. Local Temperature Trip Threshold Selection

#### \_Applications Information

#### **Remote-Diode selection**

The MAX6687/MAX6688 are optimized to measure the die temperature of CPUs and other ICs that have onchip temperature-sensing diodes. These on-chip diodes are substrate PNPs with their collectors grounded. Connect the base of the PNP to DXN and the emitter to DXP. When using a discrete, diode-connected NPN or PNP as a sensing diode, use a good-quality small-signal device. Examples are listed in Table 2. Tight specifications for forward current gain indicate the manufacturer has good process controls and that the devices have consistent VBE characteristics. Always use a transistor for the sensing junction; diodes do not work.

The MAX6687/MAX6688 are optimized for use with thermal-sensing transistors with an ideality factor of 1.008. Different ideality factors cause predictable, usually small deviations in trip temperature thresholds.

Table 2. Sensor	Transistor	Manufacturers
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MANUFACTURER	MODEL NO.
Central Semiconductor (USA)	CMPT3904
Rohm Semiconductor (Japan)	SST3904
Samsung (Korea)	KST3904-TF
Siemens (Germany)	SMBT3904

#### **Noise-Filtering Capacitors**

A quality ceramic capacitor must be connected across the DXP/DXN inputs to maintain temperature threshold accuracy by filtering out noise. The capacitor should be located physically close to the DXP/DXN pins and

should typically have a value of 2200pF. Larger capacitor values can cause temperature measurement errors. A 50% increase from the recommended capacitor value can cause up to  $\pm 1^{\circ}$ C error.

#### Sensing Circuit Board and Ambient Temperature

Temperature switches like the MAX6687/MAX6688 that sense their own die (local) temperatures must be mounted on or close to the object whose temperature they are intended to measure. The MAX6687/MAX6688 can accurately measure the temperature of a circuit board to which they are soldered because the package leads provide a good thermal path between the circuit board and their own die. If the MAX6687/MAX6688 are intended to be triggered by the temperature of a heatgenerating component on the circuit board, they should be mounted as close as possible to that component and should share supply and ground traces (if they are not noisy) with that component where possible. The thermal path between the plastic package and the die is not as good as the path through the package leads, so the MAX6687/MAX6688 are less sensitive to the surrounding air temperature than they are to the temperature of their package leads, but they can be successfully used to respond to the ambient temperature if the circuit board is designed to track the ambient temperature.

#### **Chip Information**

TRANSISTOR COUNT: 7765 PROCESS: BICMOS

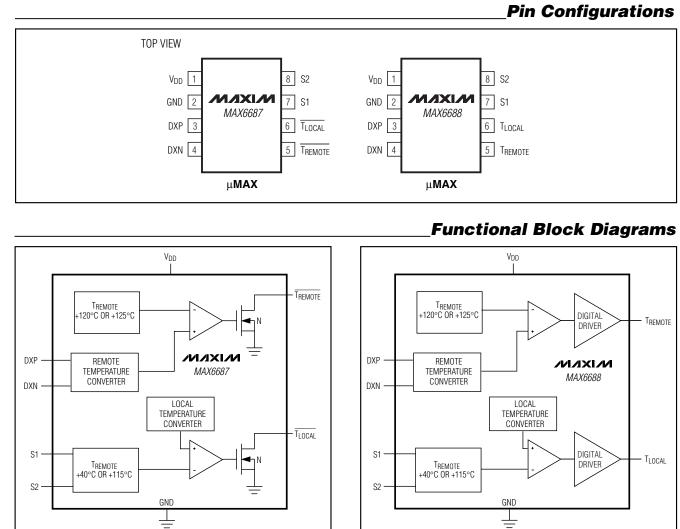


Figure 1a. MAX6687 Functional Block Diagram

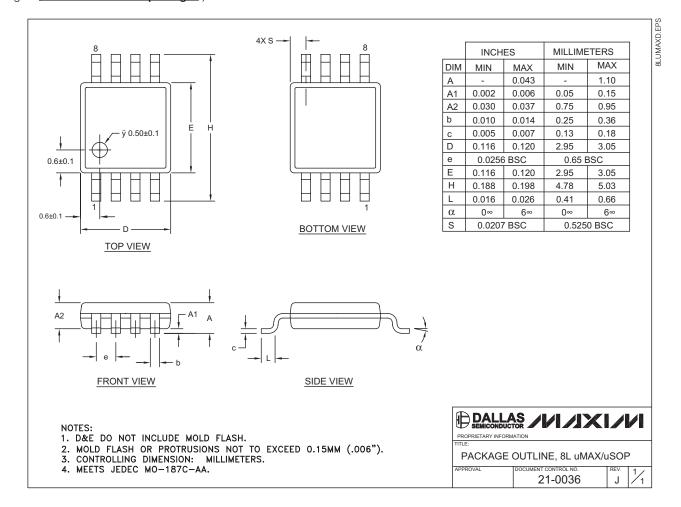
Figure 1b. MAX6688 Functional Block Diagram

#### **Selector Guide**

PART	OUTPUTS	REMOTE TRIP THRESHOLD (°C)	LOCAL TRIP THRESHOLD RANGE (°C)
MAX6687AU40L	Open drain, active low	+120	+40 to +80
MAX6687AU40H	Open drain, active low	+125	+40 to +80
MAX6687AU75L	Open drain, active low	+120	+75 to +115
MAX6687AU75H	Open drain, active low	+125	+75 to +115
MAX6688AU40L	Push pull, active high	+120	+40 to +80
MAX6688AU40H	Push pull, active high	+125	+40 to +80
MAX6688AU75L	Push pull, active high	+120	+75 to +115
MAX6688AU75H	Push pull, active high	+125	+75 to +115

## **Package Information**

(The package drawing(s) in this data sheet may not reflect the most current specifications. For the latest package outline information, go to **www.maxim-ic.com/packages**.)



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